

2SD2695,T6F(J Information



For Reference Only

Part Number 2SD2695,T6F(J

ManufacturerToshiba Semiconductor and StorageCategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - Single

Description TRANS NPN 2A 60V TO226-3 **Package** TO-226-3, TO-92-3 Long Body

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2SD2695,T6F(J Specifications

Manufacturer Part Number	2SD2695,T6F(J
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 Long Body
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	2A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 1mA, 1A
Current - Collector Cutoff (Max)	10μA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	2000 @ 1A, 2V
Power - Max	900mW
Frequency - Transition	100MHz
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 Long Body
Supplier Device Package	TO-92MOD
	Report errors?

2SD2695,T6F(J Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2SD2695,T6F(J Payment Methods





















2SD2695,T6F(J Shipping Methods













If you have any question about 2SD2695,T6F(J, please do not hesitate to contact us!

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